Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.230 inches and 0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.108 inches and 0.140 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-14
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 reverse breakdown voltage, dc
Current Rating Per Characteristic:
200.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Tuning ratio 7.4; 1 mhz; junction pattern arrangement: pn
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0